## NSN 5961-01-333-3387

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## Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

## **Overall Height:**

Between 0.250 inches and 0.450 inches

#### **Overall Width:**

1.050 inches

#### **End Application:**

Tactical air operations module an/tyq-2 (v) 1

## Mounting Facility Quantity:

2

Internal Configuration:

#### Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

## Features Provided:

Hermetically sealed case and electrostatic sensitive

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

25.00 amperes source cutoff current and 10.00 amperes source cutoff current

#### Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset

#### Transfer Ratio:

12.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

## Terminal Type And Quantity:

2 pin and 1 case

## Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

